



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

LA6581U — Monolithic Linear IC

Fan Motor Driver

BTL Driver Single-Phase Full-Wave

Overview

The LA6581U is a low-saturation BTL output linear driving motor driver for single-phase bipolar fan motors. It features quite, low power, high efficiency drive that suppresses reactive current. It is optimal for use in applications that require miniaturization and low noise, such as CPU cooling fan motors and 5 to 12V electronic game products.

Functions

- Single-phase full-wave linear drive with BTL output (gain resistance 500Ω to 284kΩ, 55dB) : Suitable for the equipment requiring silent operation, such as game equipment, CPU cooler, etc. because of its freedom from switching noise.
- Low-voltage operation possible, with wide operable voltage range (3 to 16V)
- Low saturation output (Upper + lower saturation voltage : $V_{O\text{sat}}$ (total) = 0.3V typ, I_O = 100mA) : High coil efficiency with low current drain. IC itself does not generate much heat.
- High impedance of Hall input pin
- FG output (rotation speed detection output : open collector output)
- Heat protection circuit : When the large current flows because of output short-circuit, raising the IC chip temperature above 180°C, the heat protection circuit suppresses the drive current, preventing IC burn and breakdown.
- Ultraminiature package (MSOP8J : 3.0mm×4.9mm×0.85mm typ) : Small substrate while allowing larger blades.

Specifications

Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Output voltage	V_{CC} max		18	V
Output current	I_{OUT} max	*1	0.36	A
Output withstand voltage	V_{OUT} max		18	V
FG output withstand	V_{FG} max		18	V
FG output current	I_{FG} max		5	mA

*1: This specifies the starting current. $T_j = 150^\circ\text{C}$ max must not be exceeded.

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LA6581U

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Parameter	Symbol	Conditions	Ratings	Unit
Allowable Power dissipation	Pd max	Mounted on a specified board *2	400	mW
Operating temperature	Topr		-30 to +95	°C
Storage temperature	Tstg		-55 to +150	°C

*1: Specified board: 20.0mm × 10.1mm × 0.8mm, Paper phenol, wiring density 20%.

Recommended Operating Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		2.2 to 16	V
Common-phase input voltage range of Hall input	V _{ICM}		0.3 to V _{CC} -1.5	V

Electrical Characteristics at Ta = 25°C, V_{CC} = 12.0V, unless especially specified.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Circuit current	I _{CC}	IN ⁻ = 5.8V, IN ⁺ = 6.0V, RL = ∞		14	19	mA
OUT output low voltage	V _{OL}	I _O = 100mA		0.1	0.2	V
OUT output high voltage	V _{OH}	I _O = 100mA		0.1	0.2	V
Hall bias voltage	V _{HB}	I _{HB} = 5mA	1.85	1.95	2.05	V
Hall amplifier gain	V _g		52	55	58	dB
Hall amplifier input current	V _{INR}		-10	-2	10	μA
Input offset voltage	V _{OFST}			3	6	mV
FG output low voltage	V _{FG}	I _{FG} = 3mA		0.2	0.3	V
FG output leakage current	I _{FGL}	V _{FG} = 7V			30	μA
Thermal protection circuit	Th	* Design guarantee	150	180	200	°C

* Design guarantee : Design target. Measurement with a single unit not made.

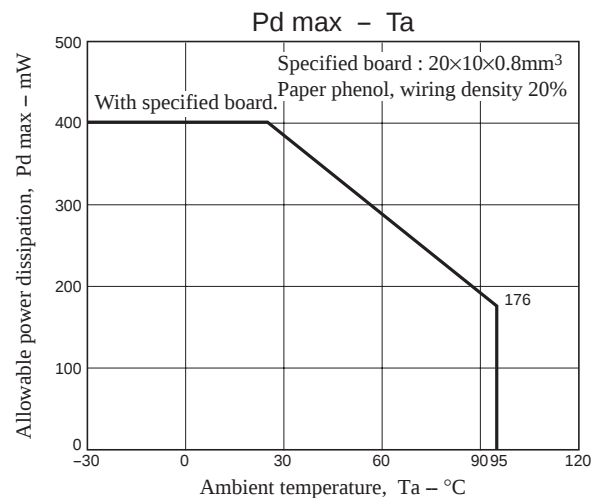
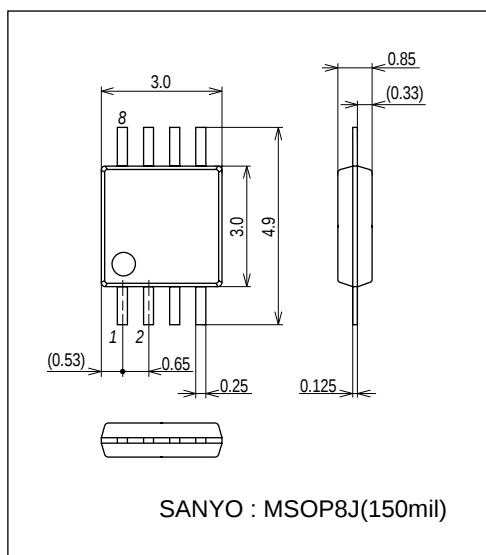
Truth Table

IN ⁻	IN ⁺	OUT1	OUT2	FG	Mode
H	L	H	L	L	During rotation
L	H	L	H	off	
—	—	off	off	—	During overheat protection

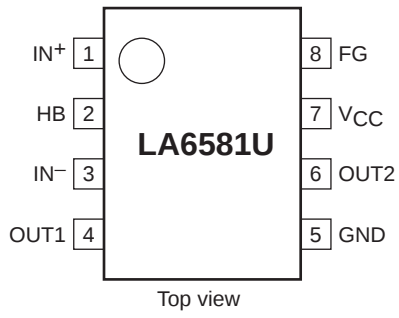
Package Dimensions

unit : mm (typ)

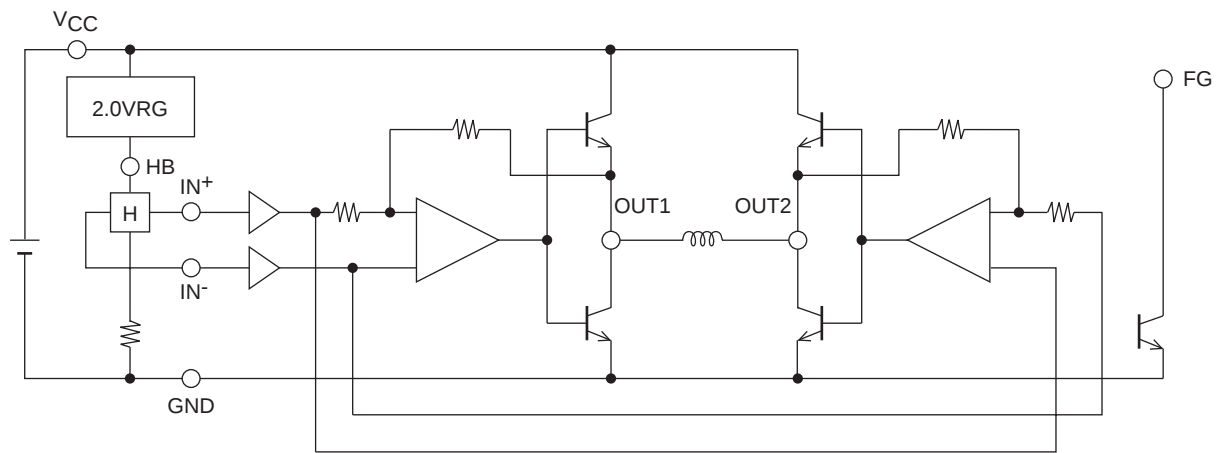
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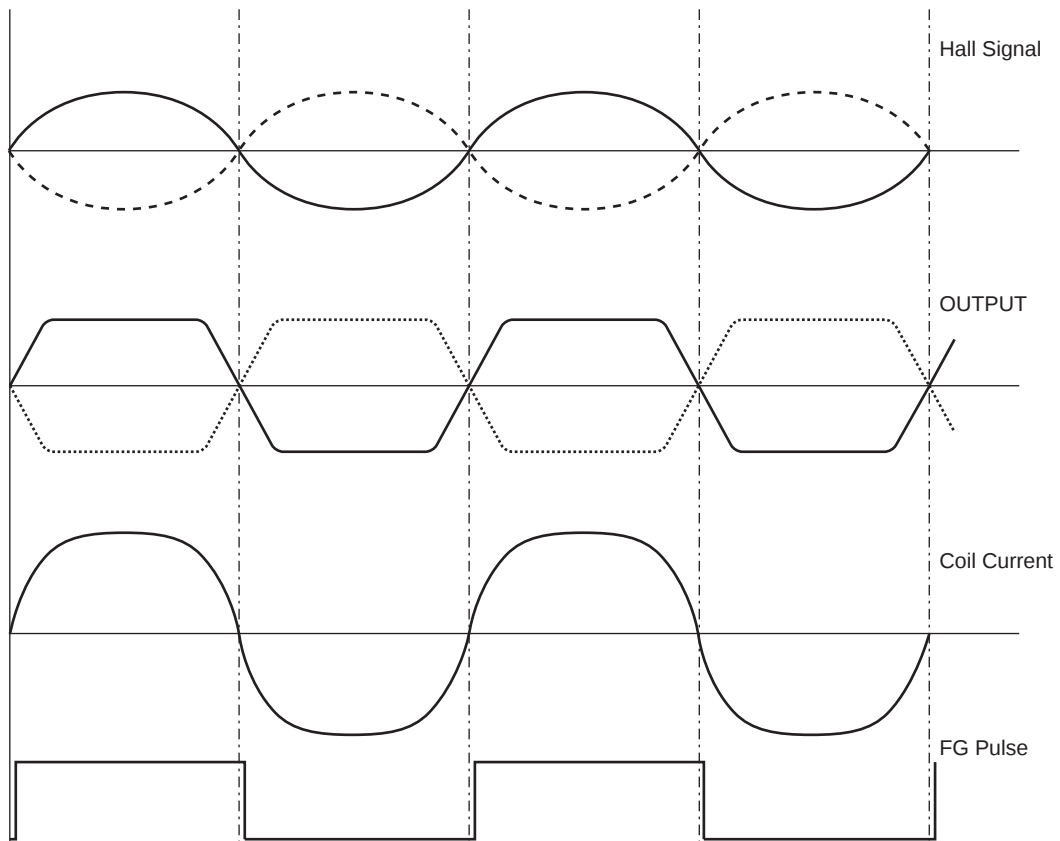
Pin Assignment



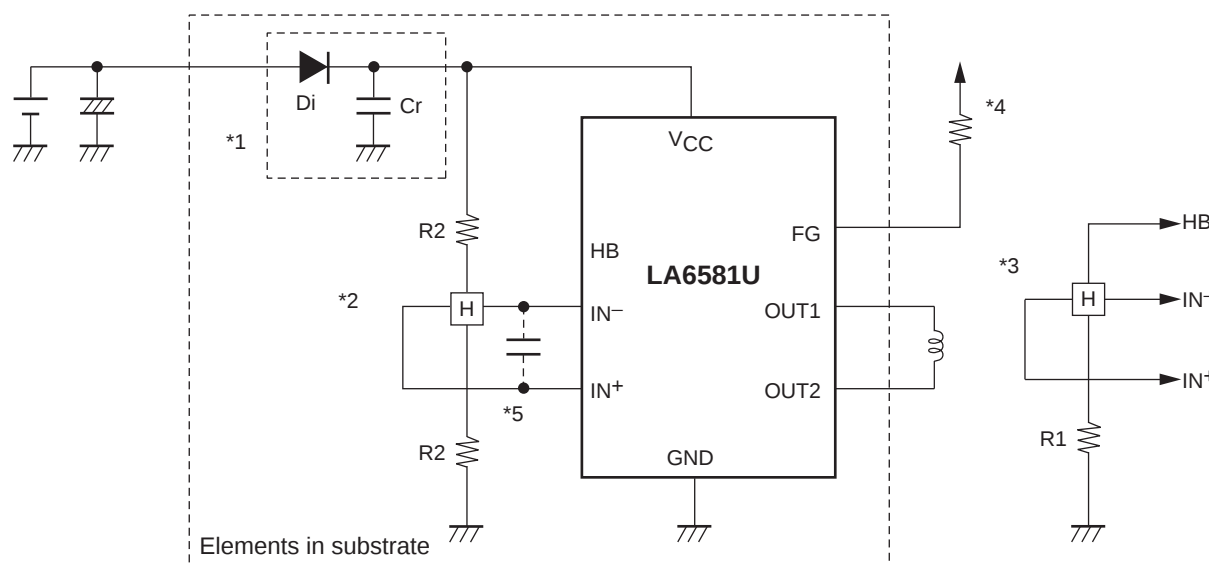
Block Diagram



Timing Chart



Sample Application Circuit



- *1 : When Di to prevent breakdown in case of reverse connection is used, it is necessary to insert a capacitor Cr to secure the regenerative current route. Similarly, Cr is necessary to enhance the reliability when there is no capacitor near the fan power line.
- *2 : To obtain Hall bias from V_{CC} , carry out $1/2 \times V_{CC}$ bias as shown in the figure. Linear driving is made through voltage control of the coil by amplifying the Hall output. When the Hall element output is large, the startup performance and efficiency are improved. Adjustment of the Hall element can reduce the noise further.
- *3 : When the Hall bias is taken from the HB pin, constant-voltage bias is made with about 2.0V. Therefore, the Hall element can provide the output satisfactory in temperature characteristics. Adjustment of the Hall output amplitude is made with R1. (When $V_{CC} = 12V$, the step *2 above proves advantageous for IC heat generation.)
- *4 : Keep this open when not used.
- *5 : When the wiring from the Hall output to IC Hall input is long, noise may be carried through the wiring. In this case, insert the capacitor as shown in the figure.

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